

## Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.24 \text{ V}$  at  $I_F = 5 \text{ A}$ 



PRIMARY CHARACTERISTICS				
$I_{F(AV)}$	2 x 30 A			
$V_{RRM}$	45 V			
I <sub>FSM</sub>	400 A			
$V_F$ at $I_F = 30$ A $(T_A = 125  ^{\circ}\text{C})$	0.41 V			
T <sub>J</sub> max.	150 °C			
Package	TO-3PW			
Diode variations	Dual common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

RoHS COMPLIANT HALOGEN

- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT60L45PW	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	45	V		
Maximum average forward rectified current (fig. 1)	per device		60	^	
	per diode	I <sub>F(AV)</sub>	30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	400	А		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.37	-	V
	I <sub>F</sub> = 15 A			0.43	-	
	I <sub>F</sub> = 30 A			0.49	0.57	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.24	-	
	I <sub>F</sub> = 15 A			0.32	-	
	I <sub>F</sub> = 30 A			0.41	0.50	
Reverse current per diode	V - 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	7	mA
	$V_R = 45 \text{ V}$ $T_A = 1$	T <sub>A</sub> = 125 °C		67	180	mA

#### Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

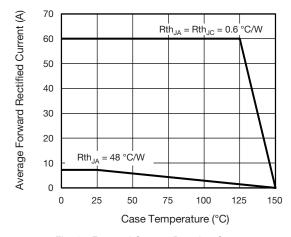
THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT60L45PW	UNIT	
Typical thermal resistance	per diode	- R <sub>θJC</sub>	0.9	°C/W	
	per device		0.6		
	per device	R <sub>θJA</sub> (1)(2)	48		

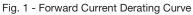
#### **Notes**

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$
- (2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PACKAGE	ACKAGE PREFERRED P/N UNIT WEIGHT (g)		PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	VT60L45PW-M3/4W	4.5	4W	30/tube	Tube	

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





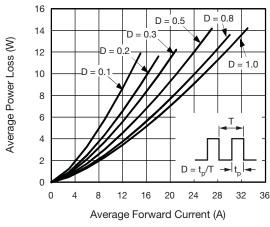


Fig. 2 - Forward Power Loss Characteristics Per Diode



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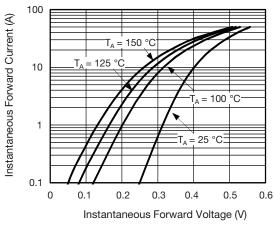


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

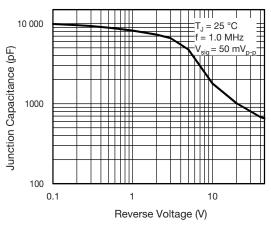


Fig. 5 - Typical Junction Capacitance Per Diode

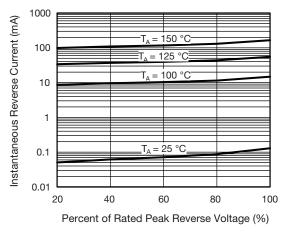


Fig. 4 - Typical Reverse Characteristics Per Diode

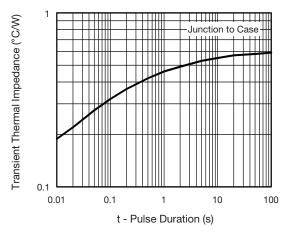
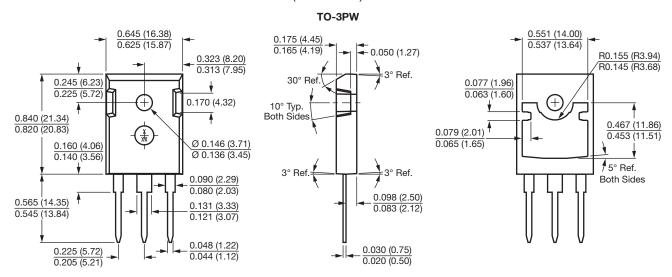


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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